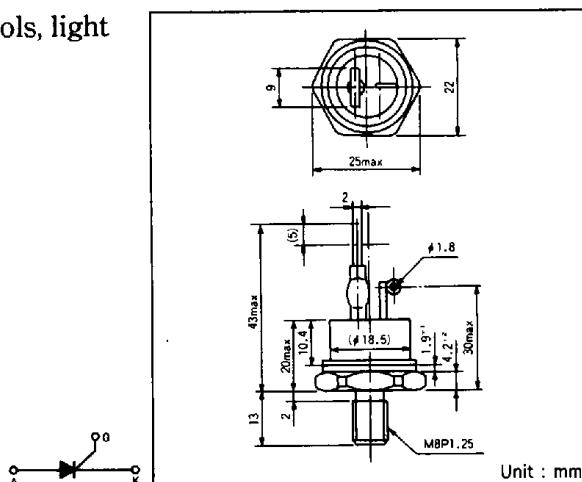


# THYRISTOR SC50C

For general phase control applications such as speed controls, light controls and welders etc.

- General power use
- $I_T = 50A$ ,  $I_{T(RMS)} = 78A$
- High voltage up to 1200V
- High surge current of 1000A
- Stud type



## ■ Maximum Ratings

Symbol	Item	SC50C-40	SC50C-60	SC50C-80	SC50C-100	SC50C-120	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage	400	600	800	1000	1200	V
$V_{RSM}$	Non-Repetitive Peak Reverse Voltage	480	720	960	1100	1300	V
$V_{DRM}$	Repetitive Peak Off-State Voltage	400	600	800	1000	1200	V

Symbol	Item	Conditions		Ratings	Unit
$I_{T(AV)}$	Average On-State Current	Single phase, half wave, 180° conduction, $T_c : 66.5^\circ C$		50	A
$I_{T(RMS)}$	R.M.S On-State Current	Single phase, half wave, 180° conduction, $T_c : 66.5^\circ C$		78	A
$I_{TSW}$	Surge On-State Current	$\frac{1}{2}$ cycle, 50Hz/60Hz, peak value, non-repetitive		900/1,000	A
$I^2t$	$I^2t$	Value for one cycle of surge current		4,160	$A^2S$
$P_{GM}$	Peak Gate Power Dissipation			10	W
$P_{G(AV)}$	Average Gate Power Dissipation			1	W
$I_{FGM}$	Peak Gate Current			3	A
$V_{FGM}$	Peak Gate Voltage(Forward)			10	V
$V_{RGM}$	Peak Gate Voltage(Reverse)			5	V
$dI/dt$	Critical Rate of Rise of On-State Current	SC50C-40~60	$I_G = 100mA$ , $T_j = 25^\circ C$ ,	50	$A/\mu s$
		SC50C-80~120	$V_D = \frac{1}{2} V_{DRM}$ , $dI/dt = 0.1A/\mu s$	200	
$T_j$	Operating Junction Temperature			-30~+125	°C
$T_{stg}$	Storage Temperature			-30~+125	°C
	Mounting Torque			70	$kgf\cdot cm$
	Mass	Excluding nut, washer 2.6g and wrapping material 0.1g		43	g

## ■ Electrical Characteristics

Symbol	Item	Conditions		Ratings	Unit
$I_{DRM}$	Repetitive Peak Off-State Current, max.	at $V_{DRM}$ , single phase, half wave, $T_j = 125^\circ C$		5	mA
$I_{RRM}$	Repetitive Peak Reverse Current, max.	at $V_{DRM}$ , single phase, half wave, $T_j = 125^\circ C$		5	mA
$V_{TM}$	Peak On-State Voltage, max.	On-State Current 150A, $T_j = 25^\circ C$ Inst. measurement		1.95	V
$I_{GT}/V_{GT}$	Gate Trigger Current/Voltage, max.	$T_j = 25^\circ C$ , $I_t = 1A$ , $V_D = 6V$		70/3	$mA/\mu s$
$V_{GD}$	Non-Trigger Gate, Voltage, min.	$T_j = 125^\circ C$ , $V_D = \frac{1}{2} V_{DRM}$		0.25	V
$t_{gt}$	Turn On Time, max	$I_t = 50A$ , $I_G = 100mA$ , $T_j = 25^\circ C$ , $V_D = \frac{1}{2} V_{DRM}$ , $dI/dt = 0.1A/\mu s$		10	$\mu s$
$dv/dt$	Critical Rate of Rise of On-State Voltage, min.	SC50C-40~60	$T_j = 125^\circ C$ , $V_D = \frac{2}{3} V_{DRM}$	100	$V/\mu s$
		SC50C-80~120	$T_j = 125^\circ C$ , $V_D = \frac{2}{3} V_{DRM}$	200	
$I_H$	Holding Current, typ.	$T_j = 25^\circ C$		30	mA
$R_{th(j-c)}$	Thermal Impedance, max.	Junction to case		0.6	$^\circ C/W$

\* mark : Thyristor and Diode part. No mark : Thyristor part

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